

KW HLL531.TE

OSLON® Black Flat S

OSLON Black Flat S is able to meet a wide range of requirements. The SMT device is very stable, durable and can be used with standard processes. A new solder pad layout allows for high reliability and improved thermal management. The compact chips not only deliver high light output, they are also individually addressable with an ensured chip-to-chip contrast which makes this LED an ideal solution for Adaptive Driving Beam (ADB).



Applications

- Headlamps, LED & Laser & Night Vision

Features:

- Package: SMD epoxy package
- Chip technology: UX:3
- Typ. Radiation: 120° (Lambertian emitter)
- Color: Cx = 0.322, Cy = 0.334 acc. to CIE 1931 (● ultra white)
- Corrosion Robustness Class: 3B
- Qualifications: The product qualification test plan is based on the guidelines of IEC60810, Lamps for road vehicles – Performance requirements – Requirements and test conditions for LED packages.
- ESD: 8 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 3B)

Ordering Information

Type	Luminous Flux ¹⁾ $I_F = 1000 \text{ mA}$ Φ_V	Ordering Code
KW HLL531.TE-Z6R9-ebvFfcbB46-RS5R	1250 ... 2240 lm	Q65112A4053

Maximum Ratings

Parameter	Symbol		Values
Operating Temperature	T_{op}	min.	-40 °C
		max.	125 °C
Storage Temperature	T_{stg}	min.	-40 °C
		max.	125 °C
Junction Temperature	T_j	max.	150 °C
Junction Temperature for short time applications*	T_j	max.	175 °C
Forward Current	I_F	min.	50 mA
$T_s = 25\text{ °C}$		max.	1500 mA
Surge Current	I_{FS}	max.	3000 mA
$t \leq 10\text{ }\mu\text{s}$; $D = 0.005$; $T_s = 25\text{ °C}$			
ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 3B)	V_{ESD}		8 kV
Reverse current ²⁾	I_R	max.	200 mA

*The median lifetime (L70/B50) for $T_j = 175\text{ °C}$ is 100h.

Characteristics

$I_F = 1000 \text{ mA}$; $T_S = 25 \text{ °C}$

Parameter	Symbol		Values
Chromaticity Coordinate ³⁾	Cx	typ.	0.322
	Cy	typ.	0.334
Viewing angle at 50 % I_V	2ϕ	typ.	120 °
Radiating surface	A_{color}	typ.	5,5 mm ²
Forward Voltage ⁴⁾ $I_F = 1000 \text{ mA}$	V_F	min.	13.55 V
		typ.	15.10 V
		max.	18.60 V
Reverse voltage (ESD device)	$V_{R \text{ ESD}}$	min.	45 V
Reverse voltage ²⁾ $I_R = 20 \text{ mA}$	V_R	max.	1.2 V
Chip to Chip Contrast	-	typ.	1:200
Real thermal resistance junction/solderpoint ⁵⁾	$R_{\text{thJS real}}$	typ.	0.90 K / W
		max.	1.10 K / W
Electrical thermal resistance junction/solderpoint ⁵⁾ with efficiency $\eta_e = 30 \text{ %}$	$R_{\text{thJS elec.}}$	typ.	0.63 K / W
		max.	0.77 K / W

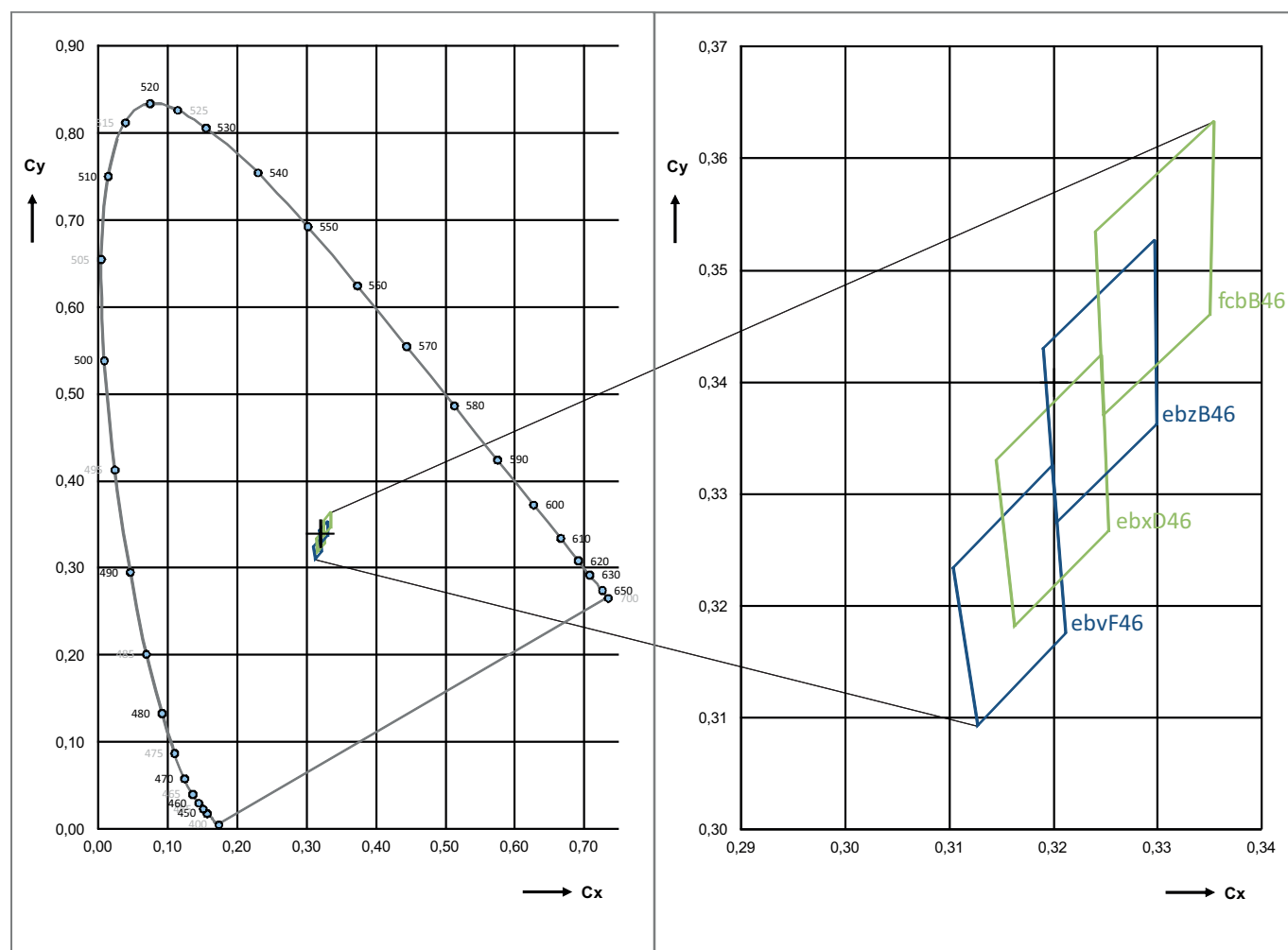
Brightness Groups

Group	Luminous Flux ¹⁾ $I_F = 1000 \text{ mA}$ min. Φ_V	Luminous Flux ¹⁾ $I_F = 1000 \text{ mA}$ max. Φ_V	Luminous Intensity ⁶⁾ $I_F = 1000 \text{ mA}$ typ. I_v
6R	1250 lm	1400 lm	437 cd
6RF	1320 lm	1490 lm	464 cd
7R	1400 lm	1590 lm	493 cd
7RF	1490 lm	1690 lm	525 cd
8R	1590 lm	1800 lm	559 cd
8RF	1690 lm	1900 lm	592 cd
5S	1800 lm	2010 lm	629 cd
5SF	1900 lm	2120 lm	663 cd
6S	2010 lm	2240 lm	701 cd

Forward Voltage Groups

Group	Forward Voltage ⁴⁾ $I_F = 1000 \text{ mA}$ min. V_F	Forward Voltage ⁴⁾ $I_F = 1000 \text{ mA}$ max. V_F
RS	13.55 V	14.85 V
KR	14.85 V	16.10 V
SR	16.10 V	17.35 V
5R	17.35 V	18.60 V

Chromaticity Coordinate Groups ³⁾



Color Chromaticity Groups ³⁾

Group	Cx	Cy	Group	Cx	Cy
ebvF46	0.3127	0.3093	ebzB46	0.3203	0.3274
	0.3212	0.3175		0.3299	0.3361
	0.3199	0.3325		0.3298	0.3526
	0.3104	0.3234		0.3190	0.3430
ebxD46	0.3163	0.3181	fcbB46	0.3248	0.3370
	0.3253	0.3266		0.3350	0.3460
	0.3246	0.3424		0.3355	0.3633
	0.3145	0.3330		0.3241	0.3534

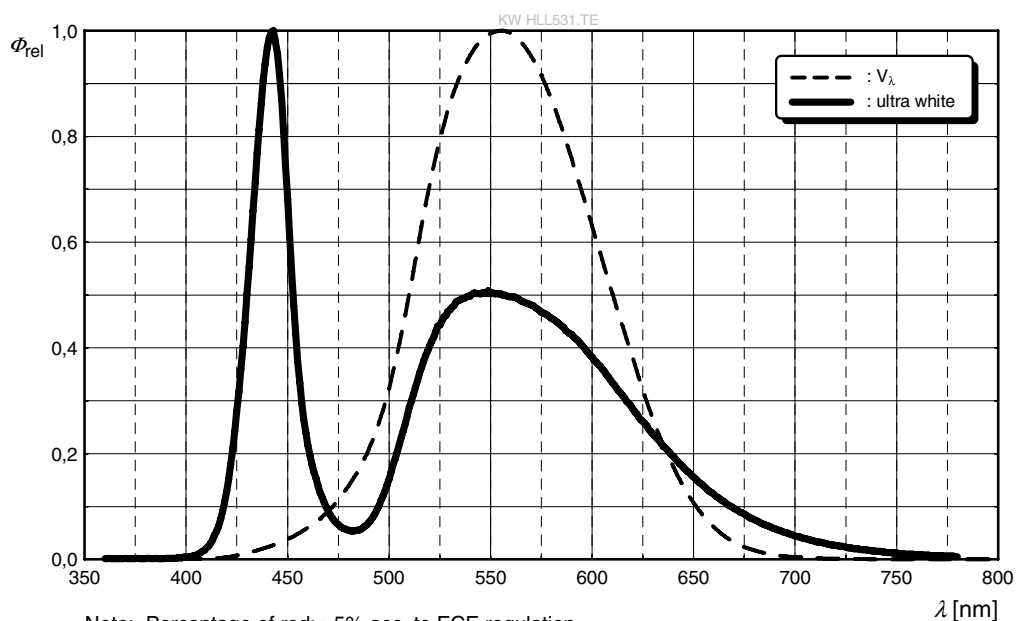
Group Name on Label

Example: 5S-ebvF46-5R

Brightness	Color Chromaticity	Forward Voltage
5S	ebvF46	5R

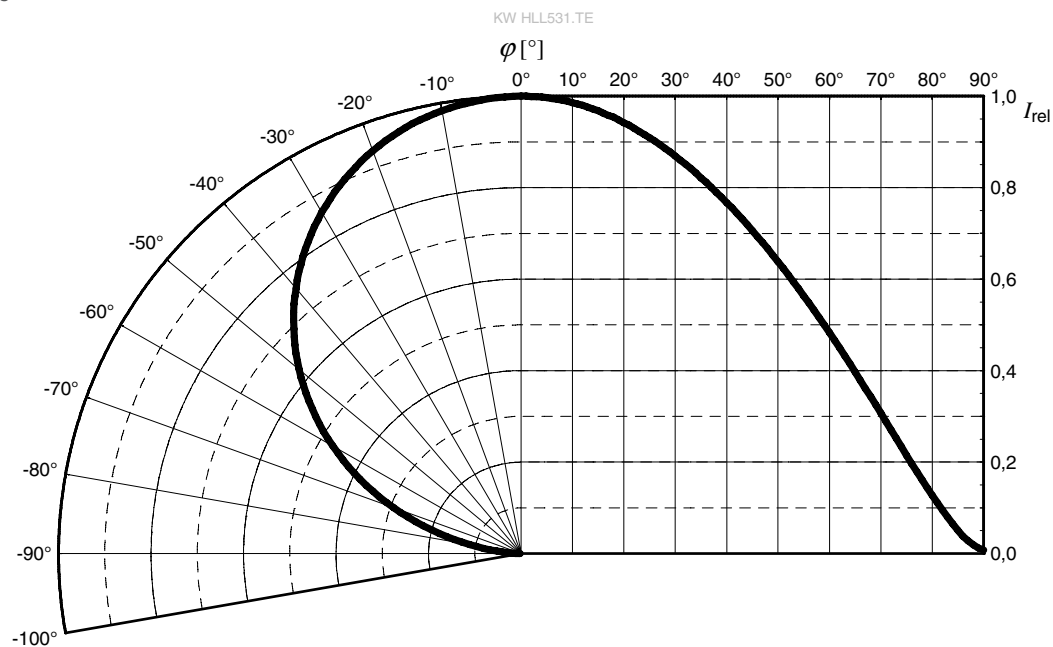
Relative Spectral Emission ⁶⁾

$$\Phi_{\text{rel}} = f(\lambda); I_F = 1000 \text{ mA}; T_S = 25^\circ \text{C}$$



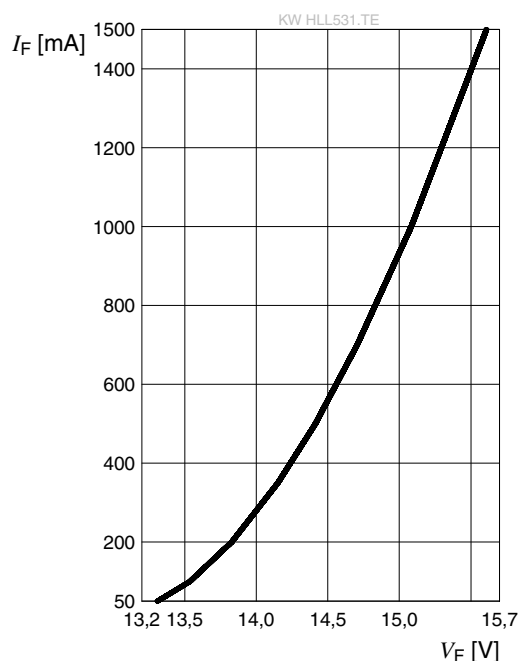
Radiation Characteristics ⁶⁾

$$I_{\text{rel}} = f(\phi); T_S = 25^\circ \text{C}$$

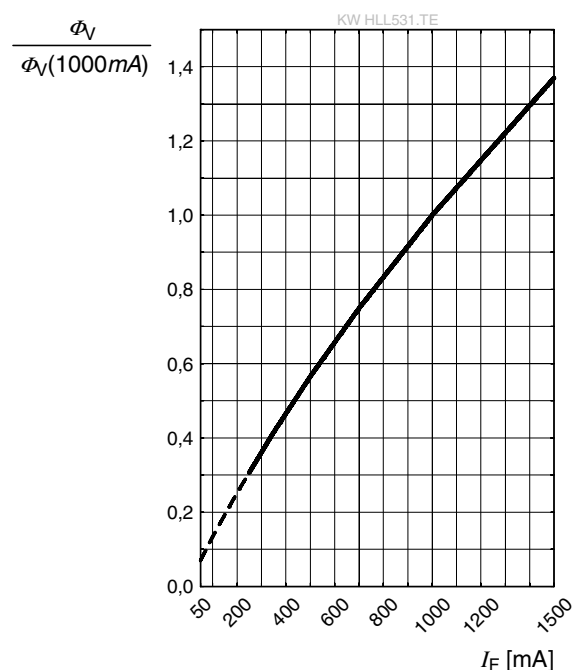


Forward current ^{6), 7)}

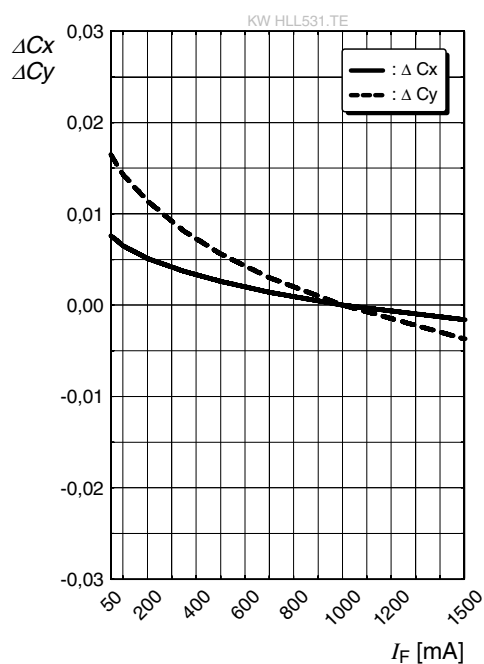
$$I_F = f(V_F); T_S = 25\text{ °C}$$

**Relative Luminous Flux** ^{6), 7)}

$$\Phi_V / \Phi_V(1000\text{ mA}) = f(I_F); T_S = 25\text{ °C}$$

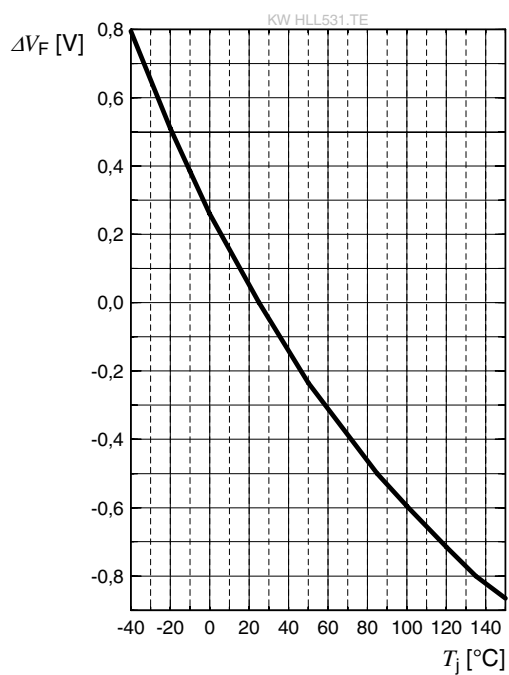
**Chromaticity Coordinate Shift** ⁶⁾

$$\Delta C_x, \Delta C_y = f(I_F); T_S = 25\text{ °C}$$



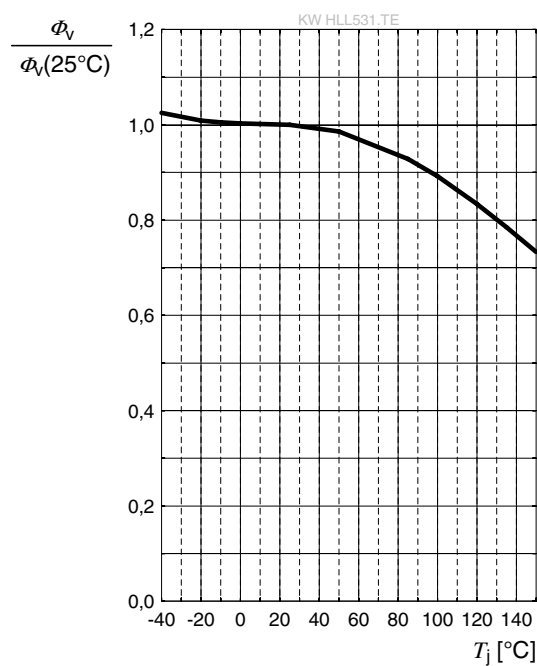
Forward Voltage ⁶⁾

$$\Delta V_F = V_F - V_F(25^\circ\text{C}) = f(T_j); I_F = 1000 \text{ mA}$$



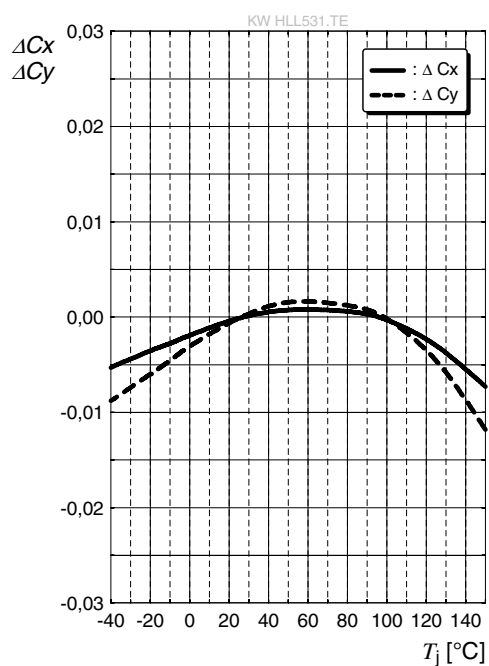
Relative Luminous Flux ⁶⁾

$$\phi_v / \phi_v(25^\circ\text{C}) = f(T_j); I_F = 1000 \text{ mA}$$



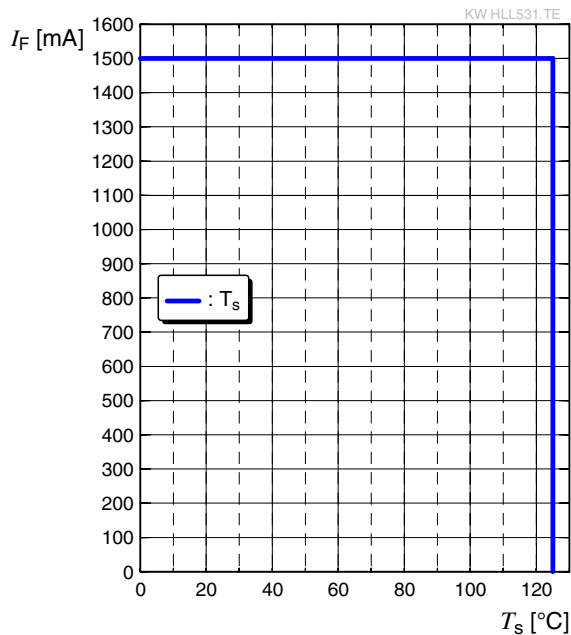
Chromaticity Coordinate Shift ⁶⁾

$$\Delta C_x, \Delta C_y = f(T_j); I_F = 1000 \text{ mA}$$



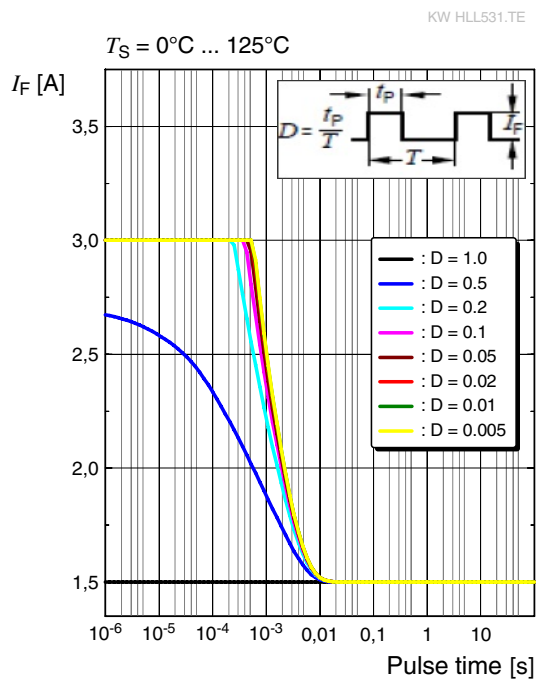
Max. Permissible Forward Current

$I_F = f(T)$; $0.7 \cdot \Phi_{V \min.}$ of bin 6R; $R_{th \text{ real max.}}$

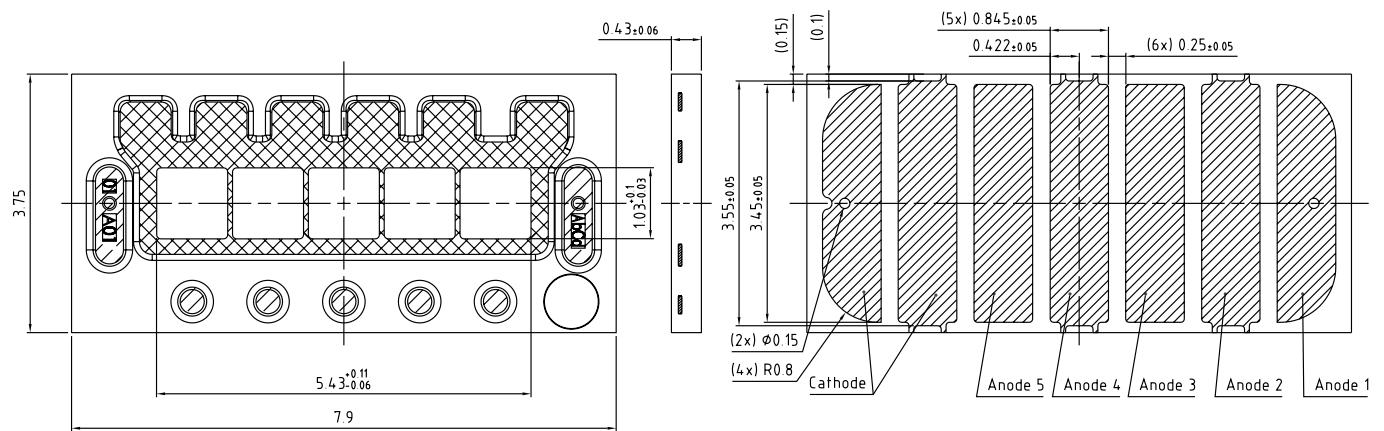


Permissible Pulse Handling Capability

$I_F = f(t_p)$; D: Duty cycle



Dimensional Drawing ⁸⁾



general tolerance ± 0.1

 Lead finish Au

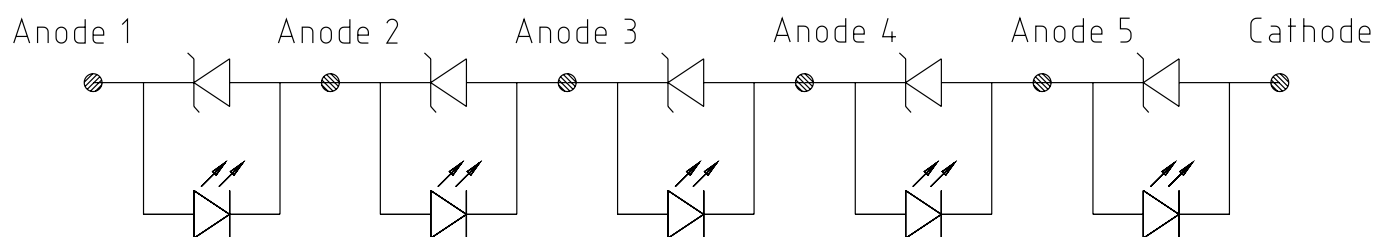
C67062-A0177-A1-04

Approximate Weight: 29.0 mg

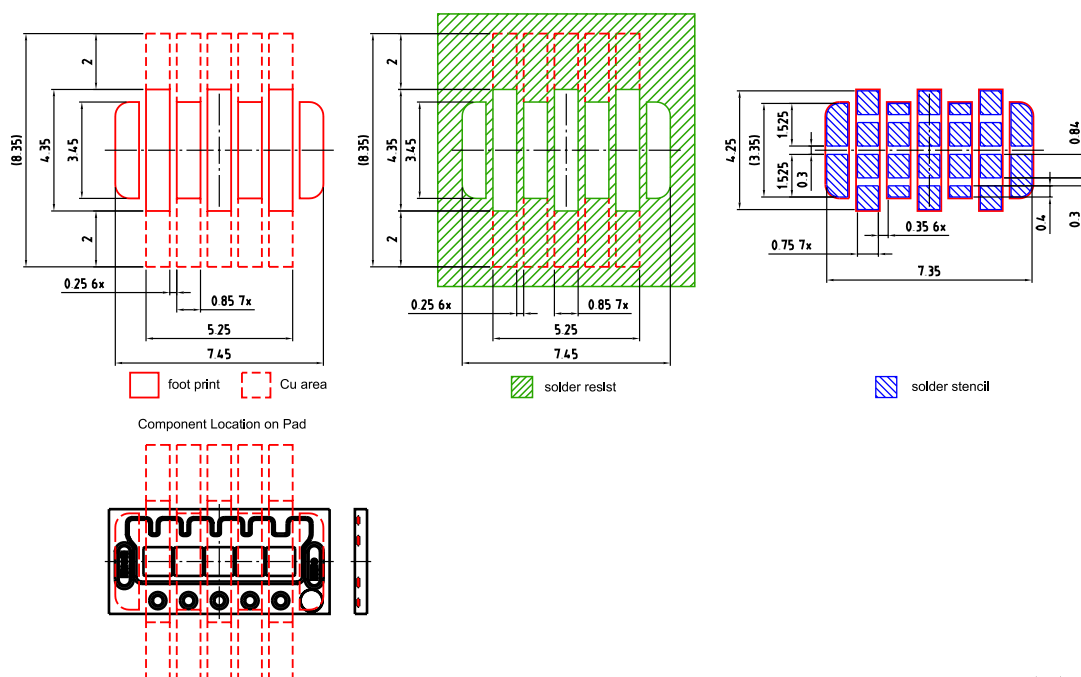
Corrosion test: Class: 3B
Test condition: 40°C / 90 % RH / 15 ppm H₂S / 14 days (stricter then IEC 60068-2-43)

ESD advice: The device is protected by ESD device which is connected in parallel to the Chip.

Electrical internal circuit



Recommended Solder Pad ⁸⁾

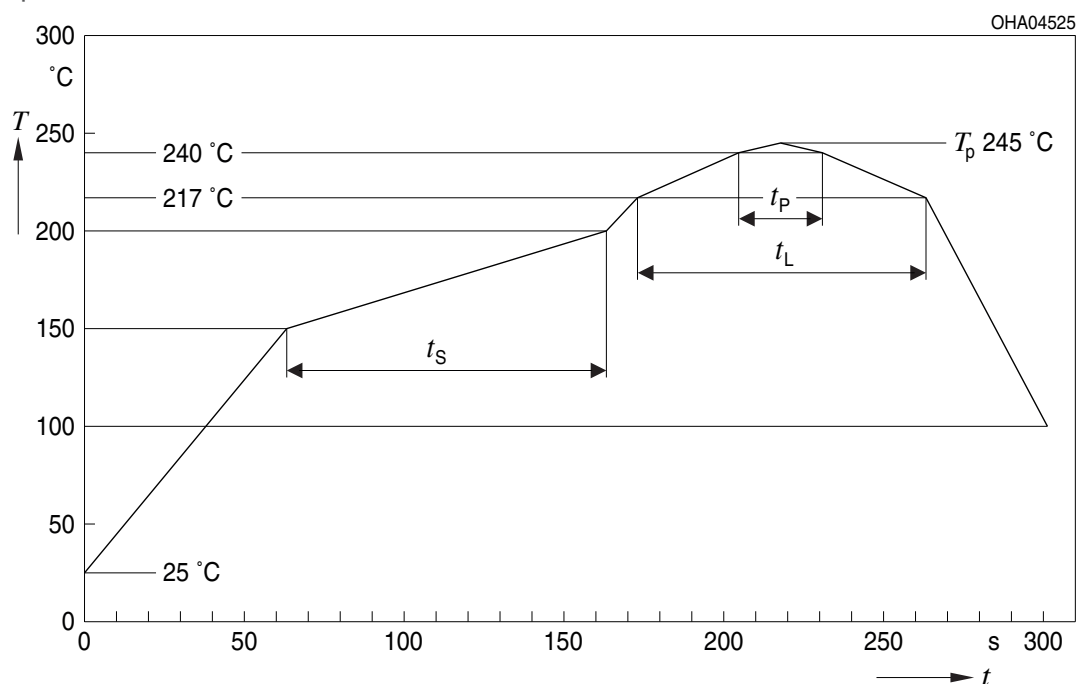


E062 3010 214 -02

For superior solder joint connectivity results we recommend soldering under standard nitrogen atmosphere. Package not suitable for ultra sonic cleaning.

Reflow Soldering Profile

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E

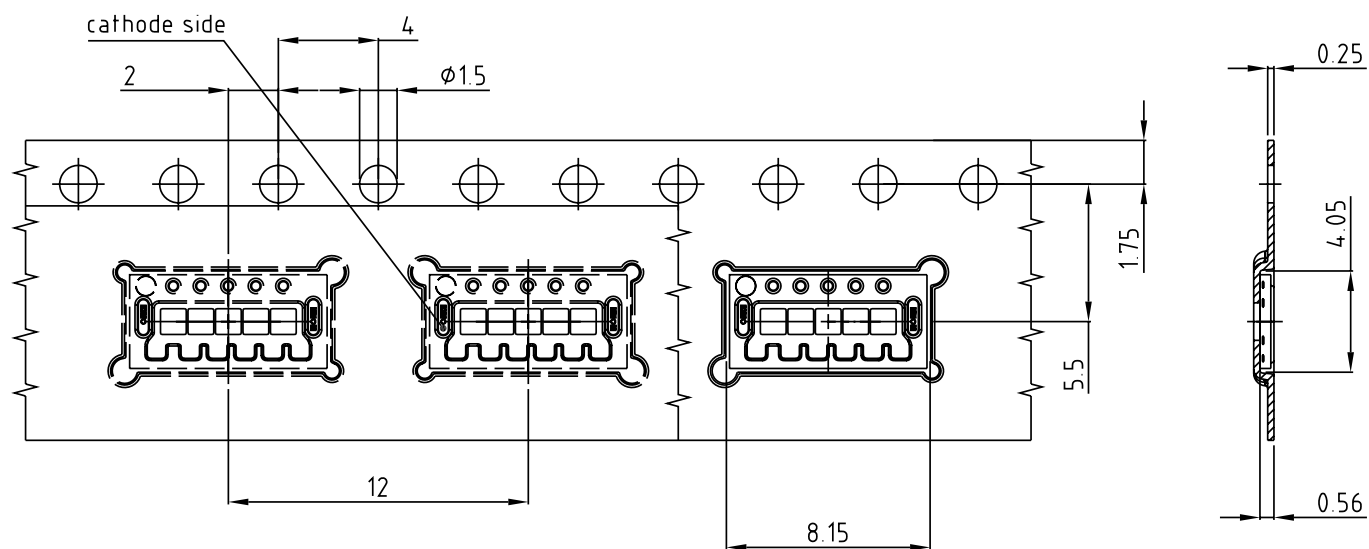


Profile Feature	Symbol	Pb-Free (SnAgCu) Assembly			Unit
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat*) 25 °C to 150 °C			2	3	K/s
Time t_s T_{Smin} to T_{Smax}	t_s	60	100	120	s
Ramp-up rate to peak*) T_{Smax} to T_p			2	3	K/s
Liquidus temperature	T_L		217		$^{\circ}\text{C}$
Time above liquidus temperature	t_L		80	100	s
Peak temperature	T_p		245	260	$^{\circ}\text{C}$
Time within 5 °C of the specified peak temperature $T_p - 5\text{ K}$	t_p	10	20	30	s
Ramp-down rate* T_p to 100 °C			3	6	K/s
Time 25 °C to T_p				480	s

All temperatures refer to the center of the package, measured on the top of the component

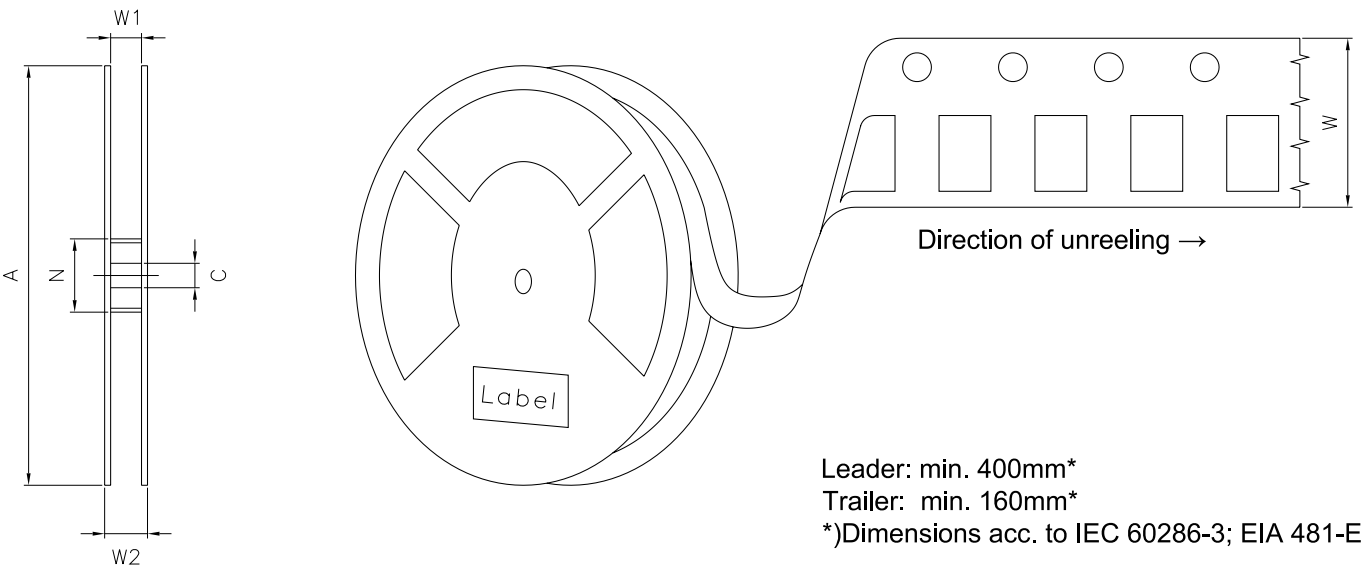
* slope calculation DT/Dt : Dt max. 5 s; fulfillment for the whole T-range

Taping ⁸⁾



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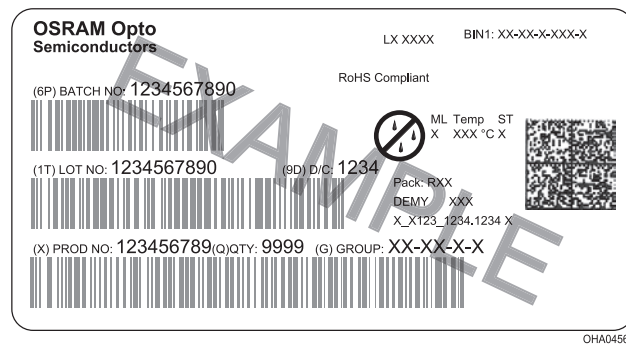
Tape and Reel ⁹⁾



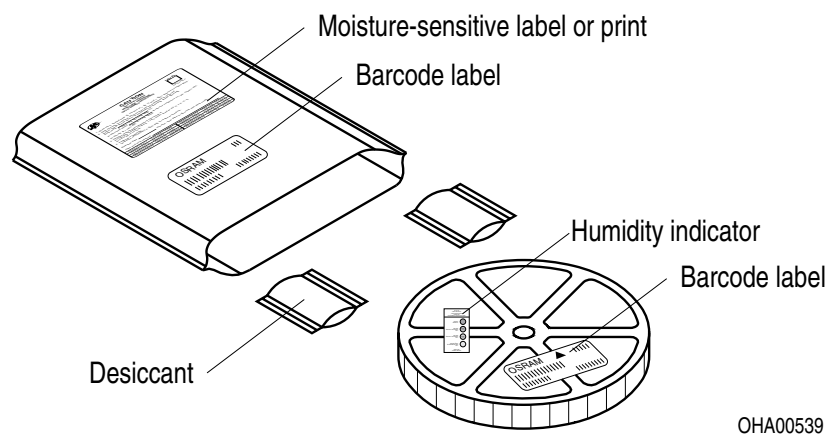
Reel dimensions [mm]

A	W	N _{min}	W ₁	W _{2 max}	Pieces per PU
180 mm	12 + 0.3 / - 0.1	60	12.4 + 2	18.4	1200

Barcode-Product-Label (BPL)

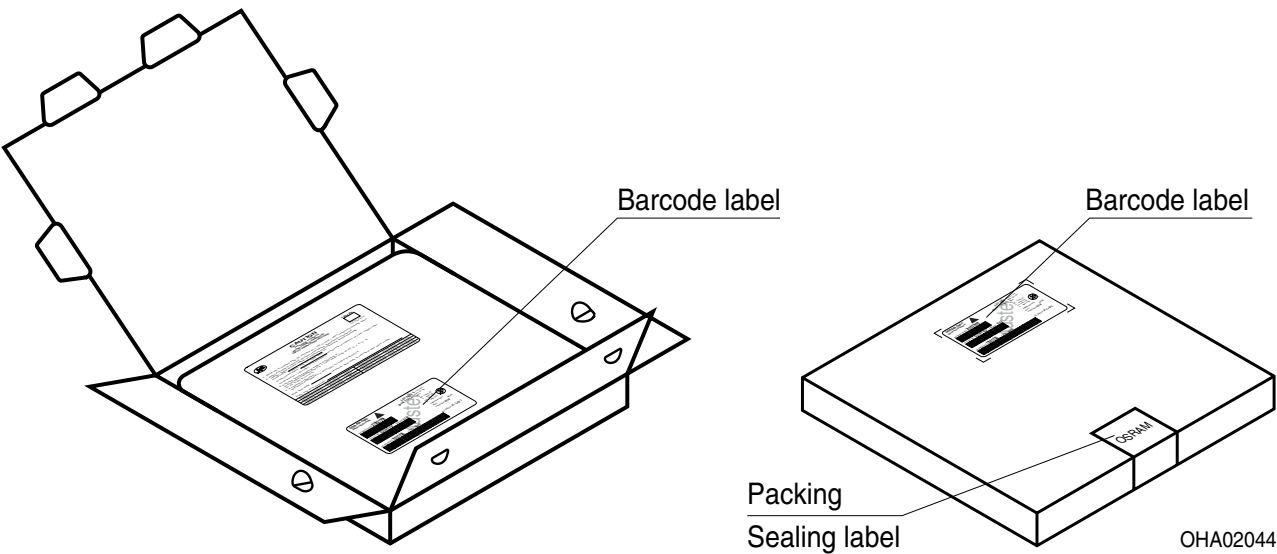


Dry Packing Process and Materials ⁸⁾



Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.

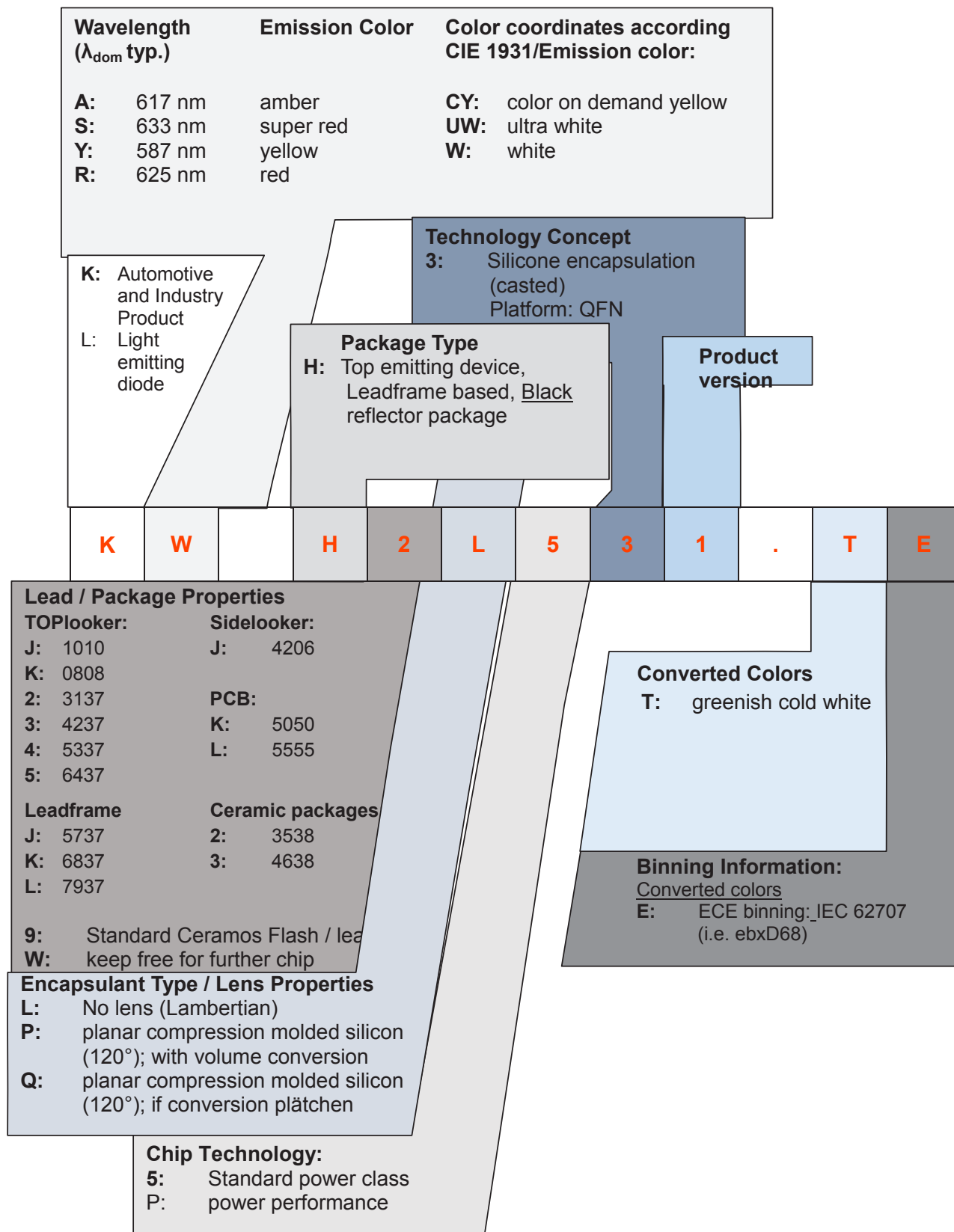
Transportation Packing and Materials ⁸⁾



Dimensions of transportation box in mm

Width	Length	Height
195 ± 5 mm	195 ± 5 mm	30 ± 5 mm

Type Designation System



Notes

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet falls into the class **moderate risk (exposure time 0.25 s)**. Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this LED contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize LED exposure to aggressive substances during storage, production, and use. LEDs that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related informations please visit www.osram-os.com/appnotes

Disclaimer

Disclaimer

Language english will prevail in case of any discrepancies or deviations between the two language wordings.

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on the OSRAM OS website.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office.

By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product safety devices/applications or medical devices/applications

OSRAM OS components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

In case Buyer – or Customer supplied by Buyer– considers using OSRAM OS components in product safety devices/applications or medical devices/applications, Buyer and/or Customer has to inform the local sales partner of OSRAM OS immediately and OSRAM OS and Buyer and /or Customer will analyze and coordinate the customer-specific request between OSRAM OS and Buyer and/or Customer.

Glossary

- 1) **Brightness:** Brightness values are measured during a current pulse of typically 25 ms, with an internal reproducibility of $\pm 8\%$ and an expanded uncertainty of $\pm 11\%$ (acc. to GUM with a coverage factor of $k = 3$).
- 2) **Reverse Operation:** Reverse Operation of 10 hours is permissible in total. Continuous reverse operation is not allowed.
- 3) **Chromaticity coordinate groups:** Chromaticity coordinates are measured during a current pulse of typically 25 ms, with an internal reproducibility of ± 0.005 and an expanded uncertainty of ± 0.01 (acc. to GUM with a coverage factor of $k = 3$).
- 4) **Forward Voltage:** The forward voltage is measured during a current pulse of typically 8 ms, with an internal reproducibility of $\pm 0.05\text{ V}$ and an expanded uncertainty of $\pm 0.1\text{ V}$ (acc. to GUM with a coverage factor of $k = 3$).
- 5) **Thermal Resistance:** $R_{th\text{ max}}$ is based on statistic values (6σ).
- 6) **Typical Values:** Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- 7) **Characteristic curve:** In the range where the line of the graph is broken, you must expect higher differences between single devices within one packing unit.
- 8) **Tolerance of Measure:** Unless otherwise noted in drawing, tolerances are specified with ± 0.1 and dimensions are specified in mm.
- 9) **Tape and Reel:** All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.

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EU RoHS and China RoHS compliant product



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按照中国的相关法规和标准，不含有毒有害物质或元素。